

MALVINO & BATES

**Electronic
PRINCIPLES**

SEVENTH EDITION



Transistor Fundamentals



Topics Covered in Chapter 7

- **Variations in current gain**
- **The load line**
- **The operating point**
- **Recognizing saturation**
- **The transistor switch**

Topics Covered in Chapter 7 (Continued)

- **Emitter bias**
- **LED drivers**
- **The effect of small changes**
- **Troubleshooting**
- **More optoelectronic devices**

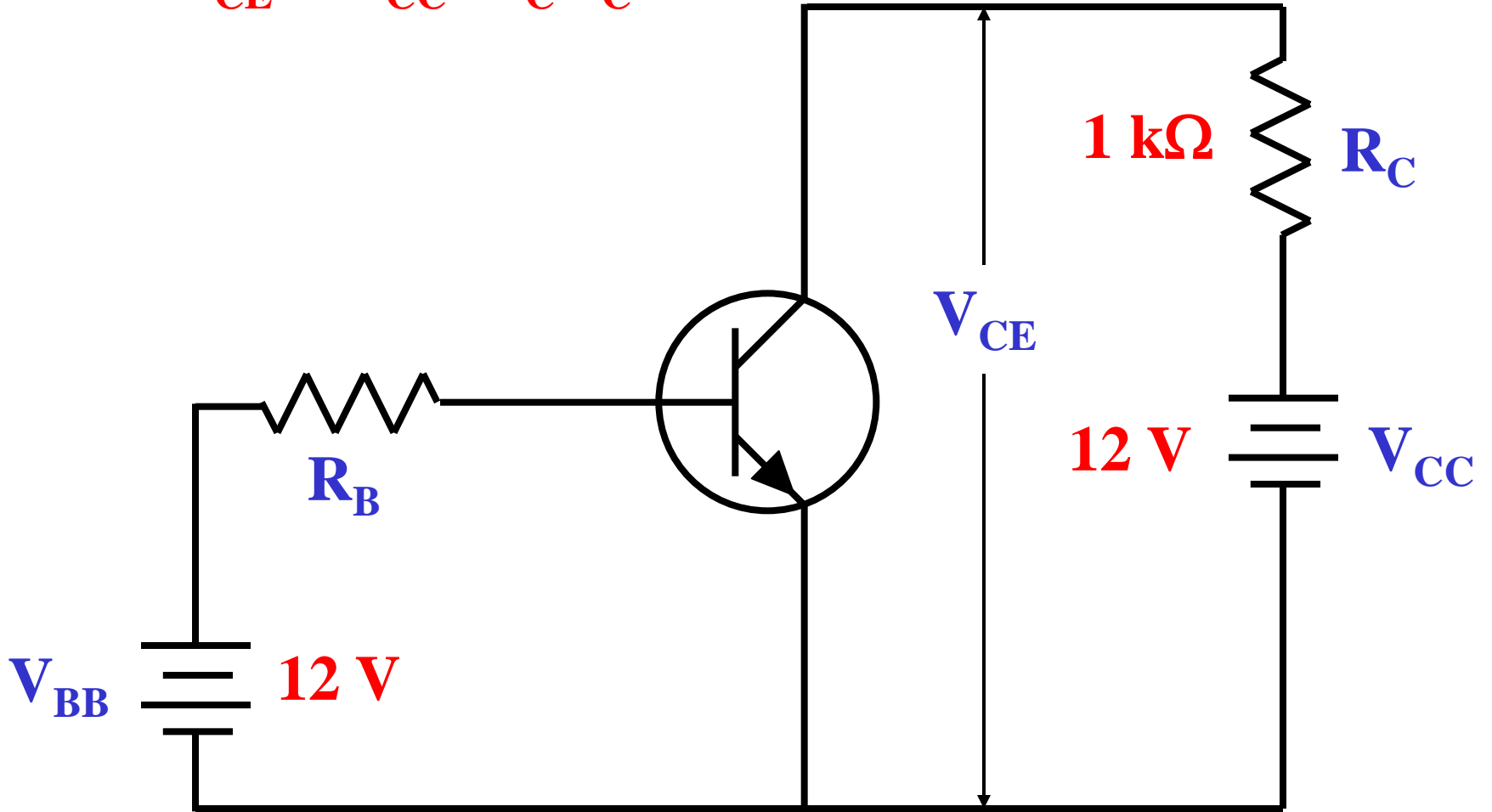
Current gain

- **Depends on:**
 - ✓ **Transistor**
 - ✓ **Collector current**
 - ✓ **Temperature**

Base bias

- Setting up a fixed value of **base** current
- Base supply voltage (V_{BB}) divided by base resistor (R_B)

$$V_{CE} = V_{CC} - I_C R_C$$

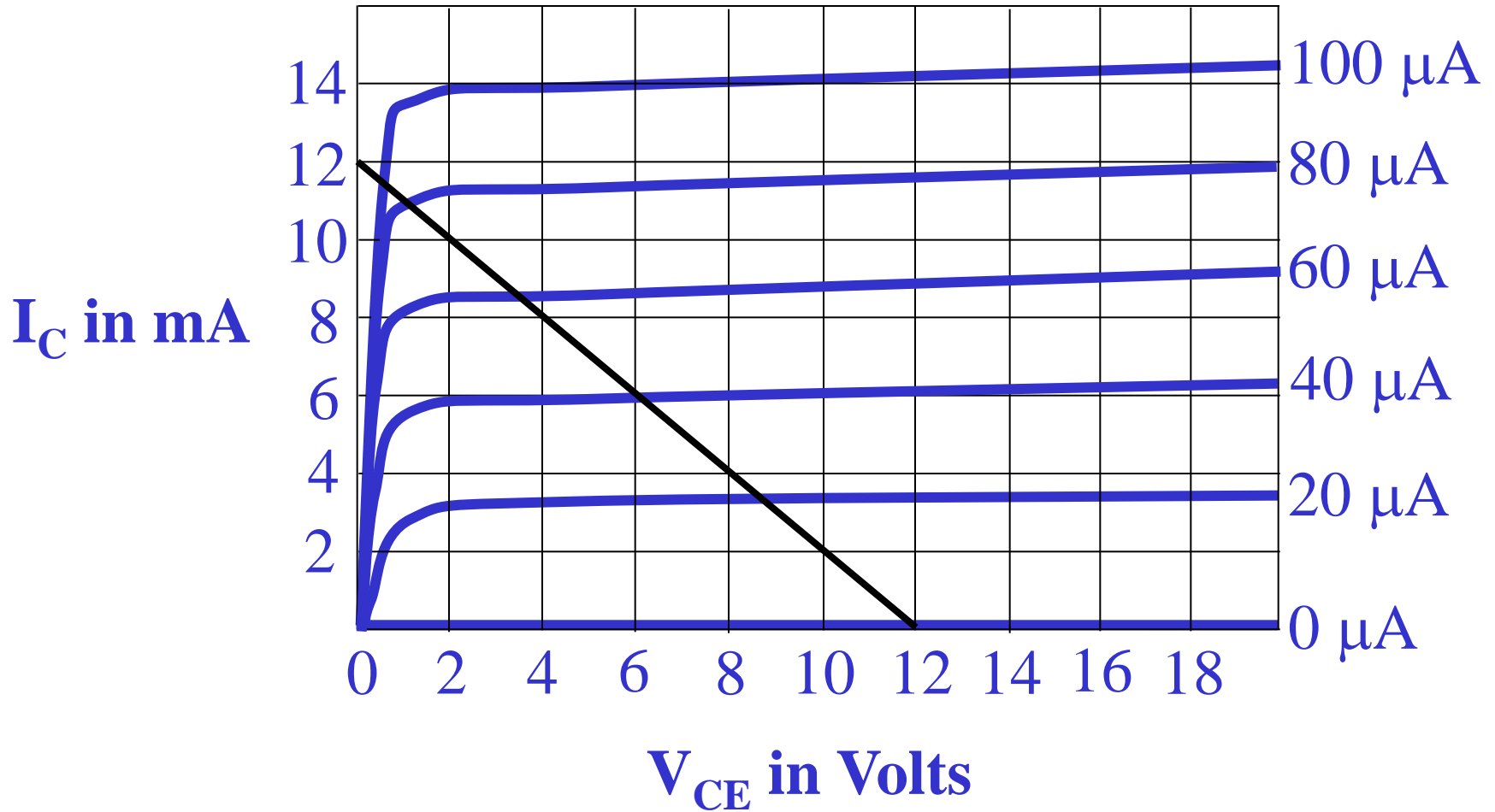


Load line

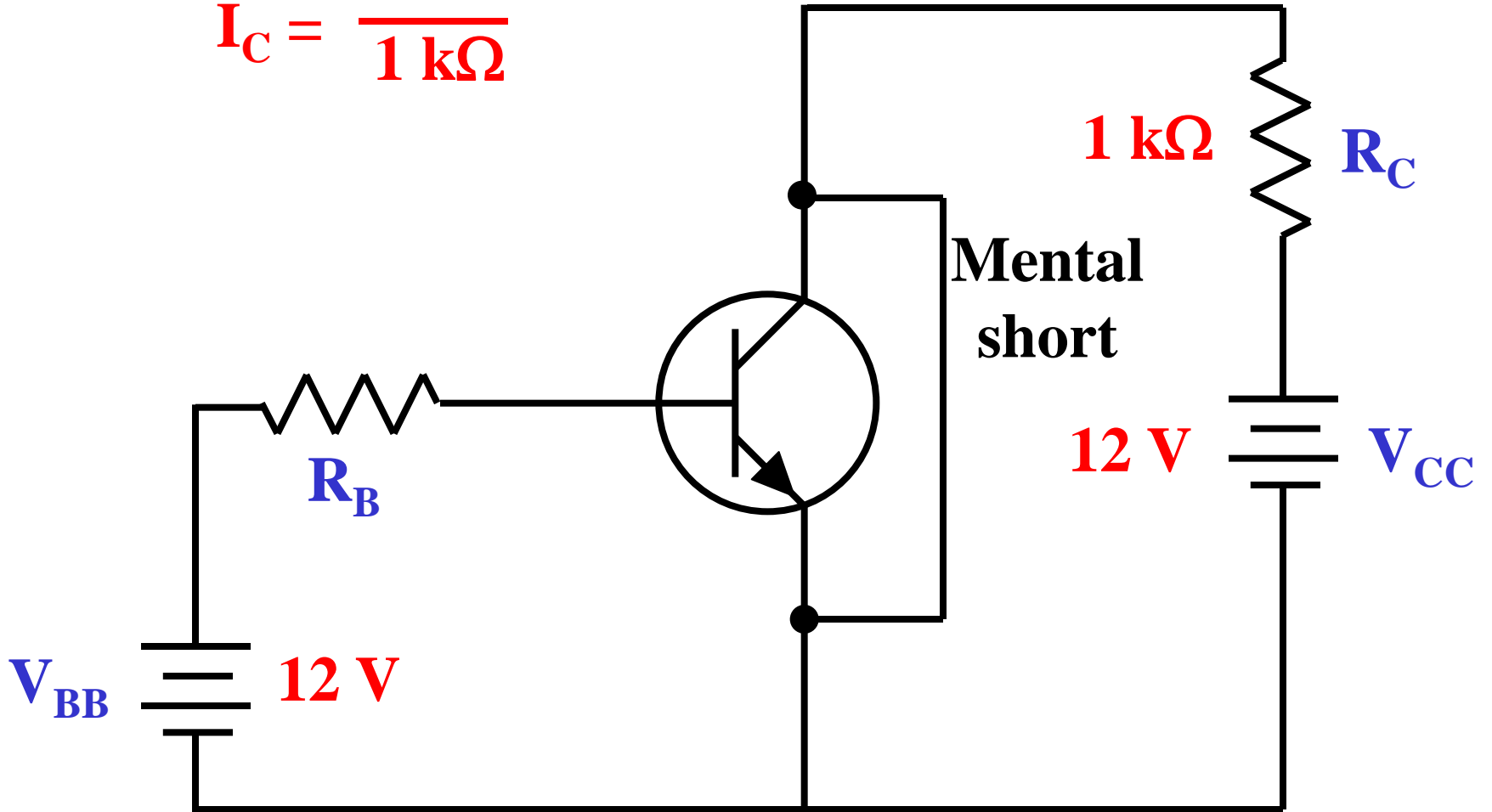
- Connects saturation current (I_{Csat}) to cutoff voltage ($V_{CEcutoff}$)
- A visual summary of all the possible transistor operating points

$$I_C = \frac{V_{CC} - V_{CE}}{R_C}$$

A graph of this equation produces a load line.

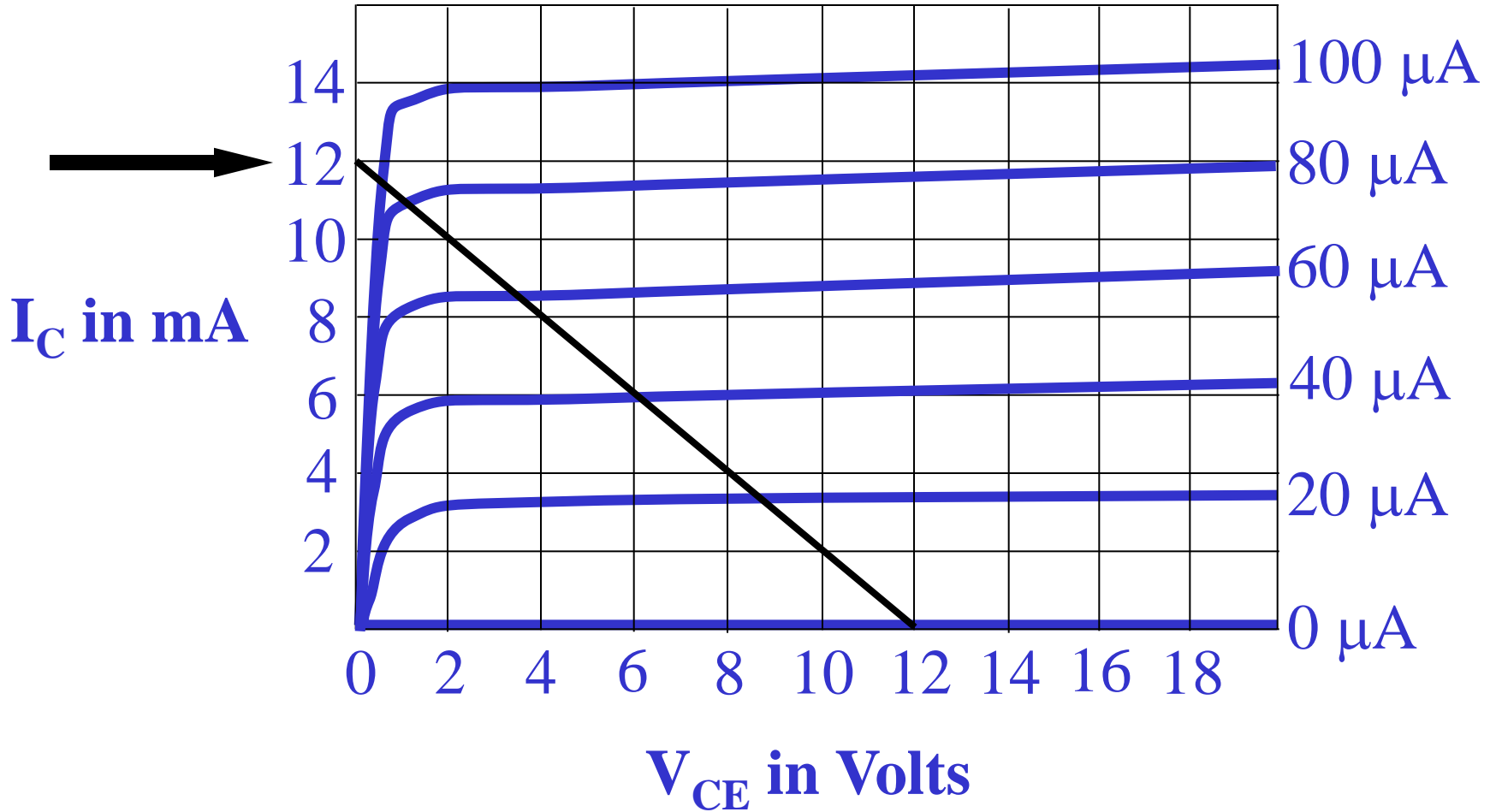


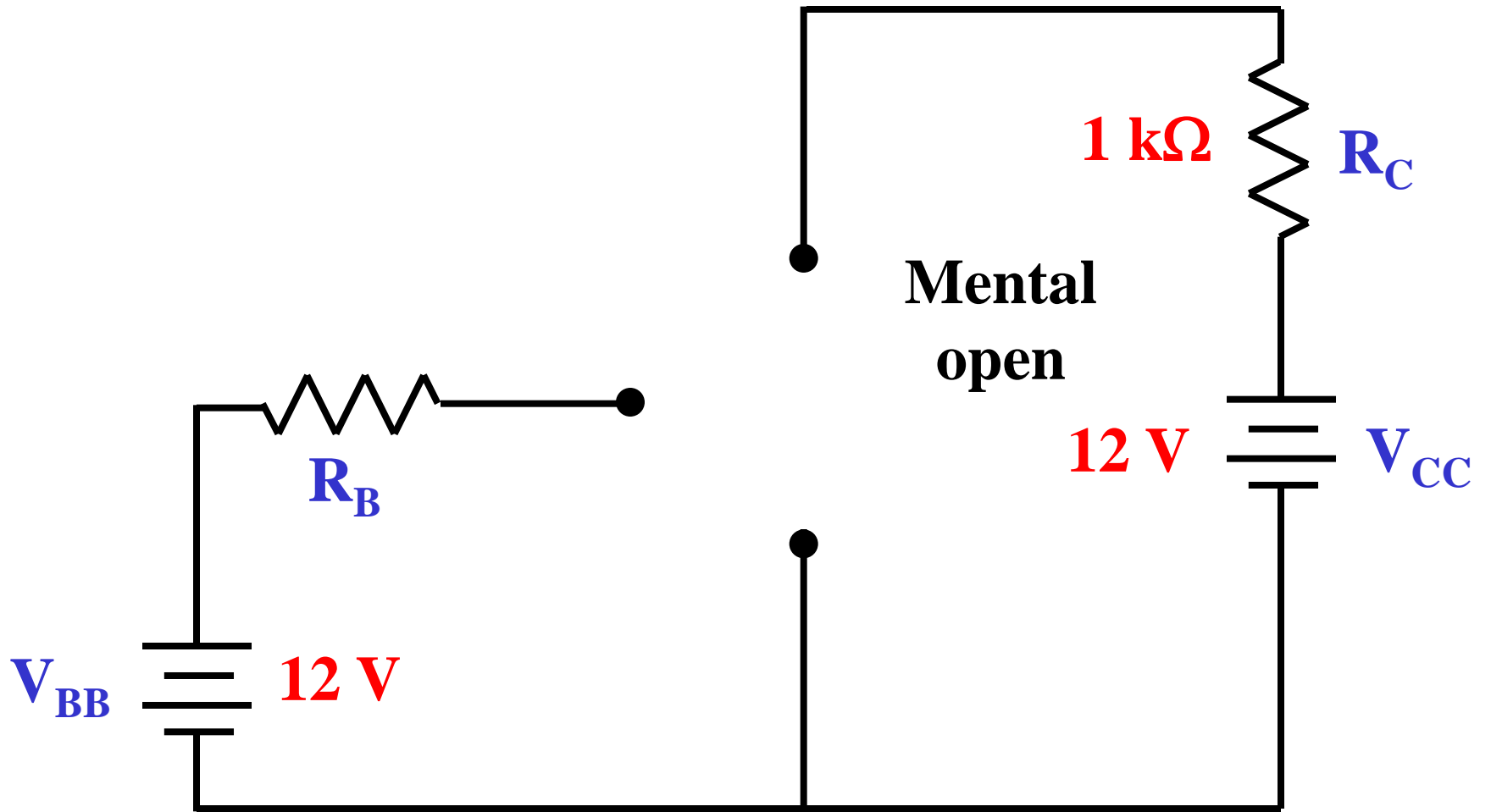
$$I_C = \frac{12\text{ V}}{1\text{ k}\Omega}$$



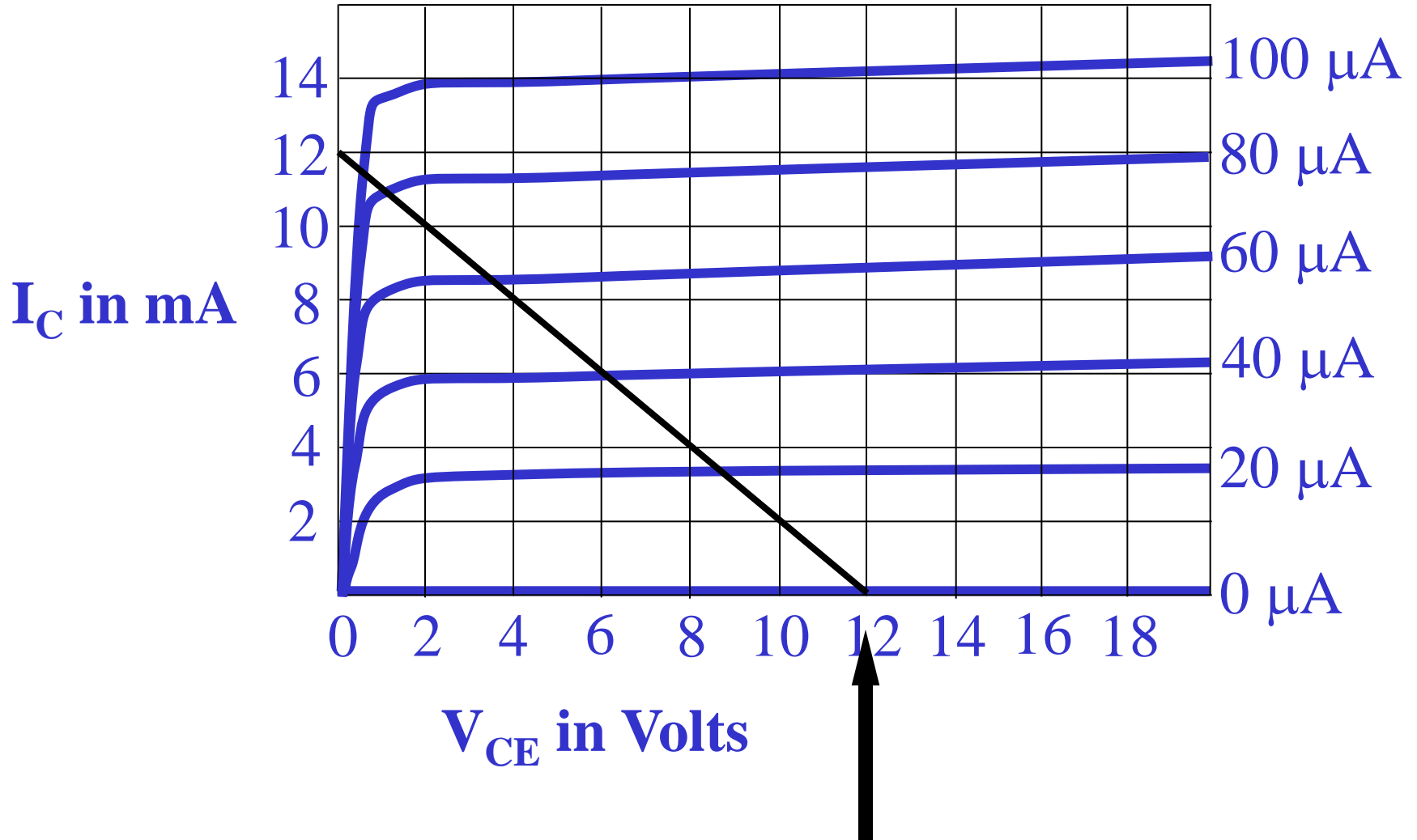
$$I_C = \frac{12\text{ V}}{1\text{ k}\Omega} = 12\text{ mA}$$

This is the
Saturation (maximum) current.





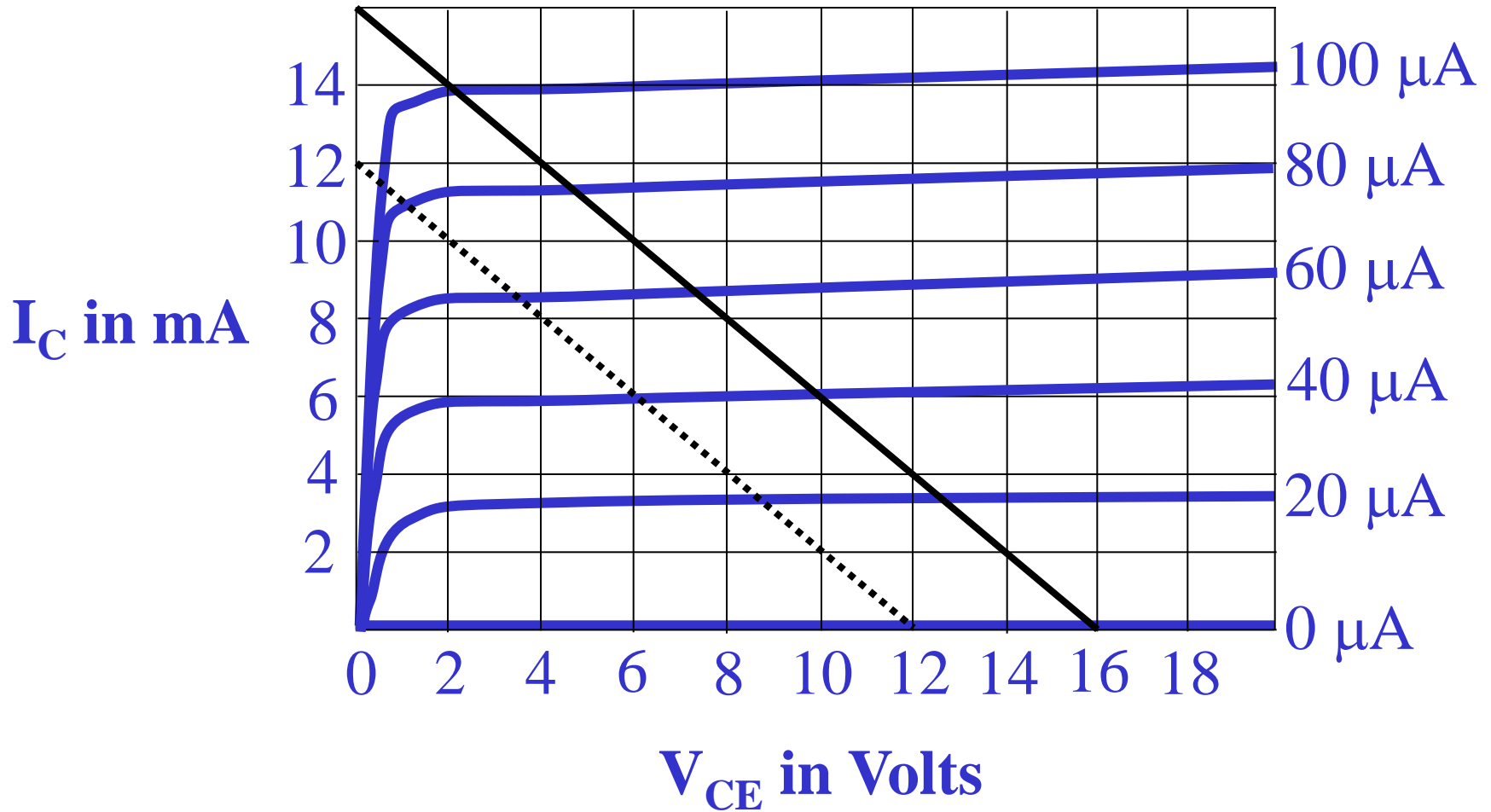
$$V_{CE(\text{cutoff})} = V_{CC}$$



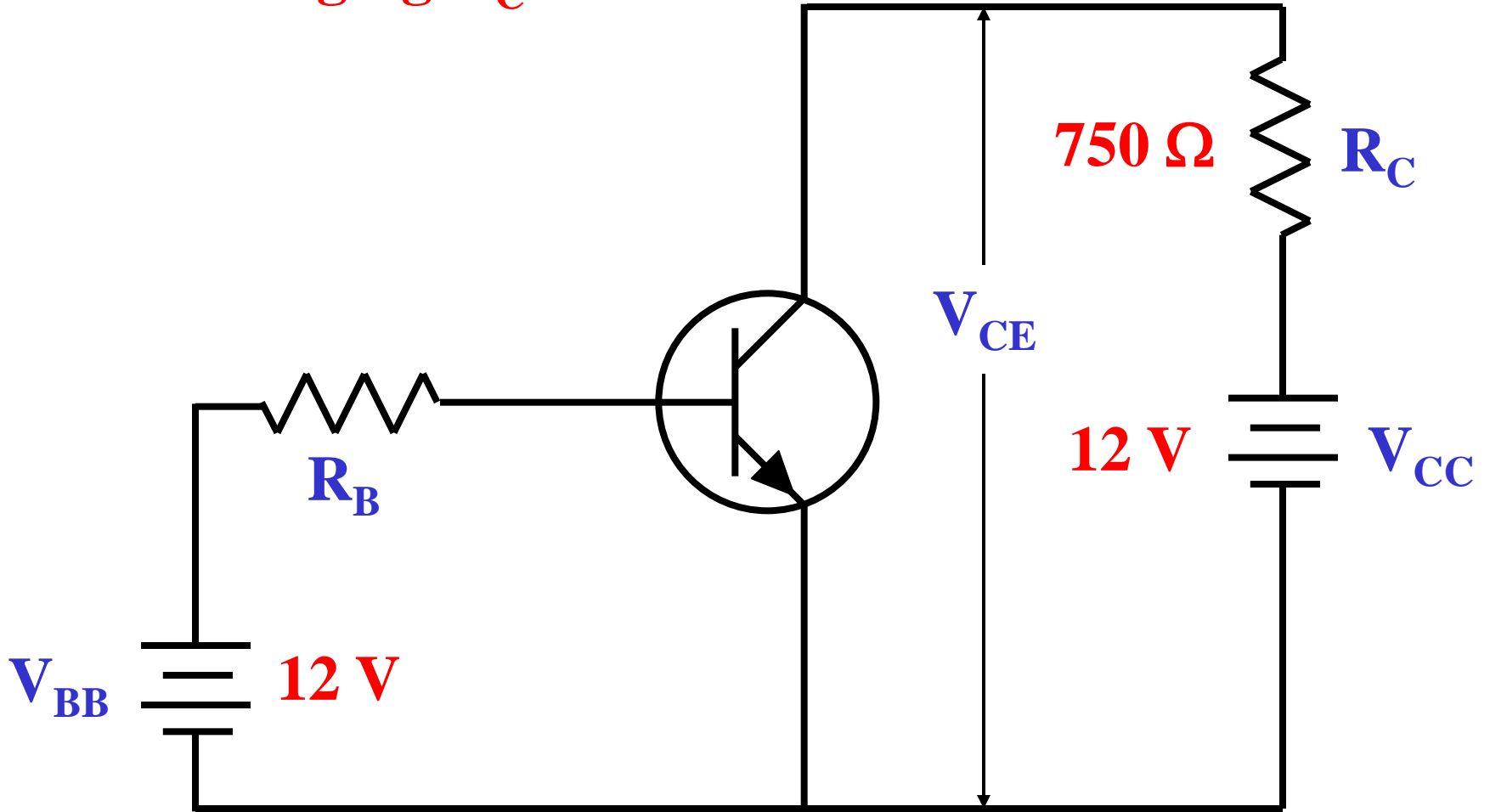
Load line slope

- Changing the collector supply voltage while keeping the same collector resistance produces two **load lines**
- These load lines will have the same slope but will have different saturation and **cutoff** values

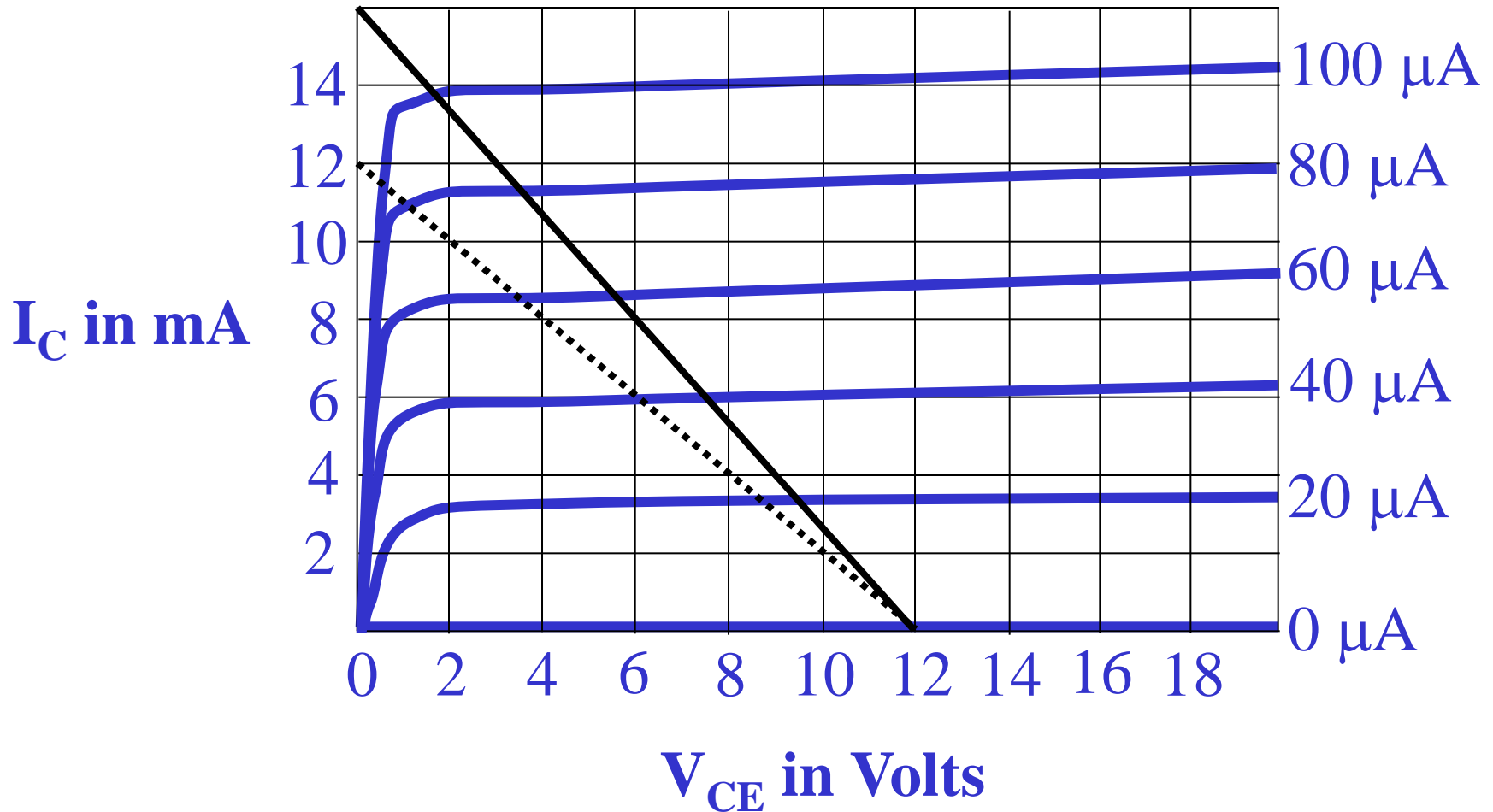
Same slope with new I_{Csat} and $V_{CEcutoff}$



Changing R_C :



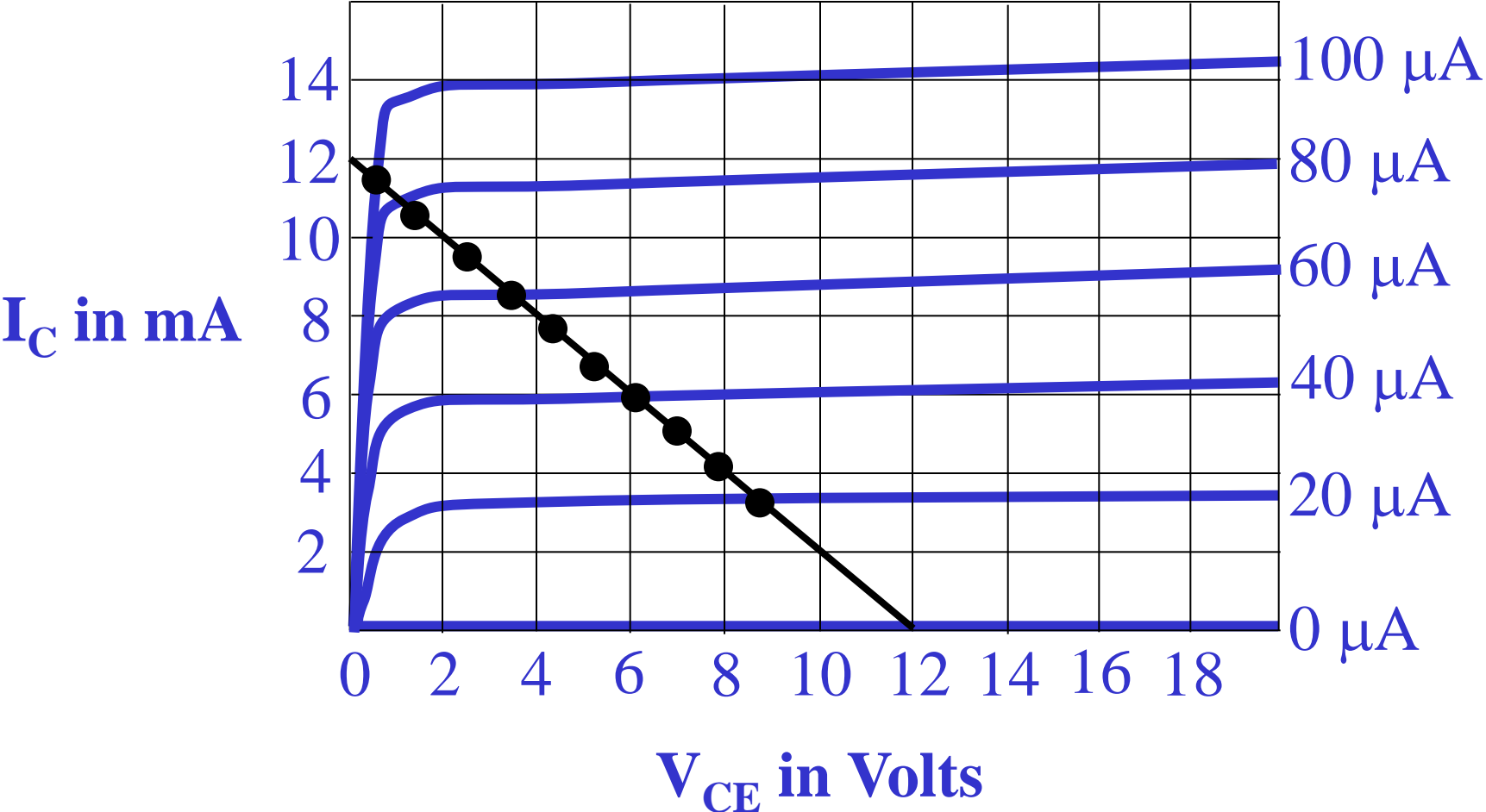
A smaller R_C produces a higher value I_{Csat} and a steeper slope



Operating point

- Determined by:
 - ✓ Finding **saturation** current and **cutoff** voltage points
 - ✓ Connecting points to produce a **load** line
 - ✓ The operating (Q) point is established by the value of **base** current

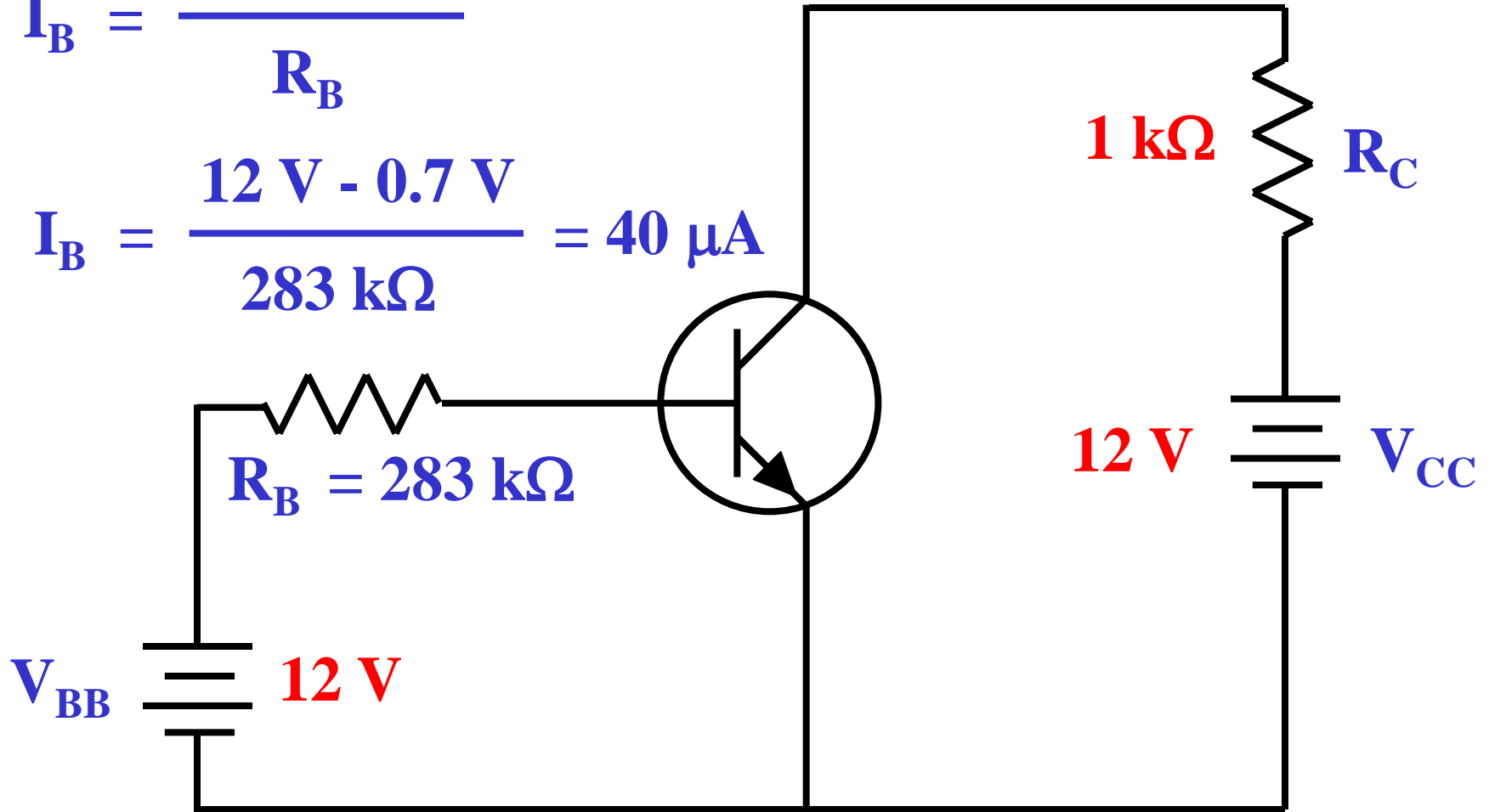
A circuit can operate at any point on the load line.



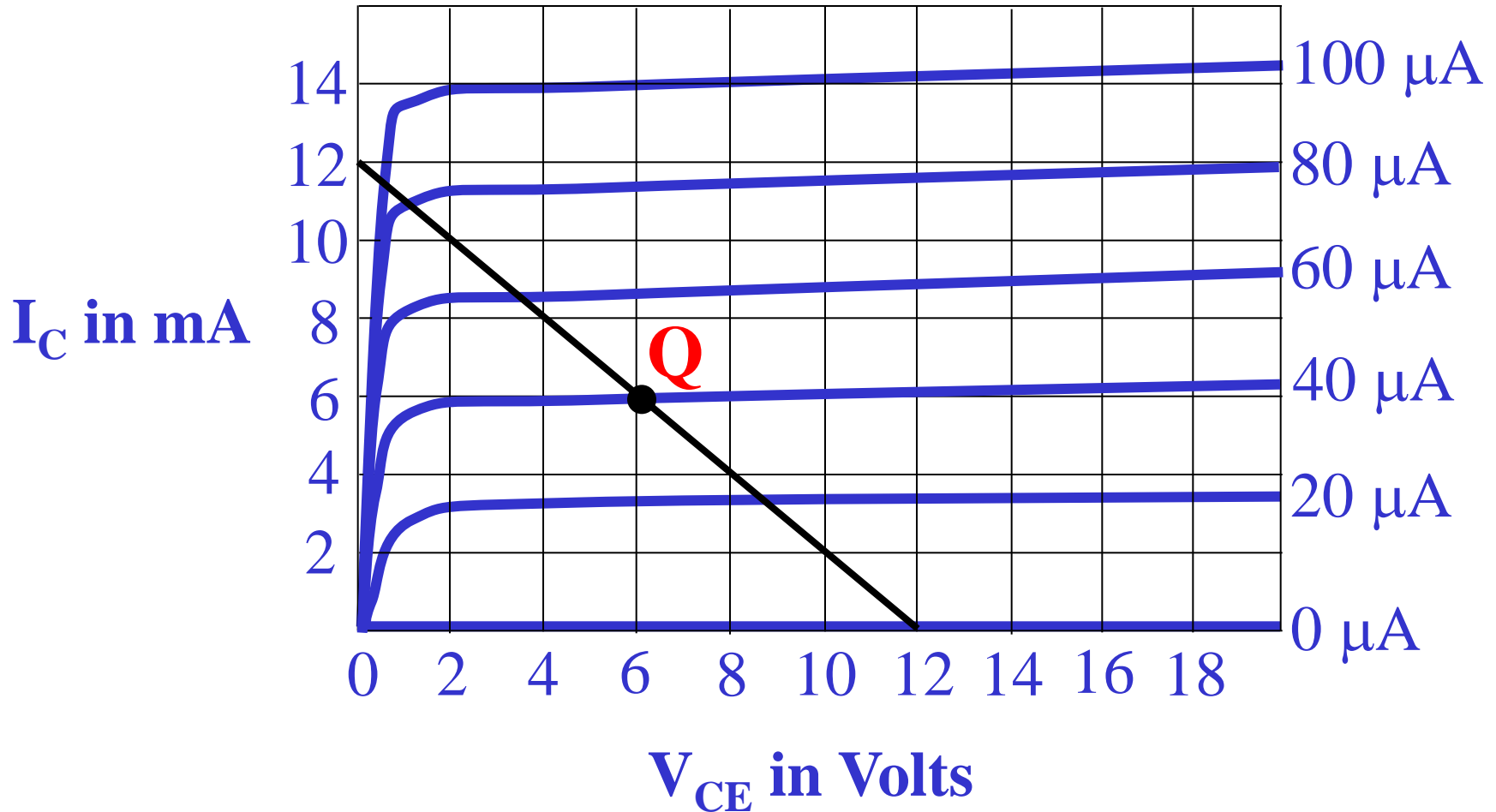
The operating point is determined by the base current.

$$I_B = \frac{V_{BB} - V_{BE}}{R_B}$$

$$I_B = \frac{12 \text{ V} - 0.7 \text{ V}}{283 \text{ k}\Omega} = 40 \mu\text{A}$$

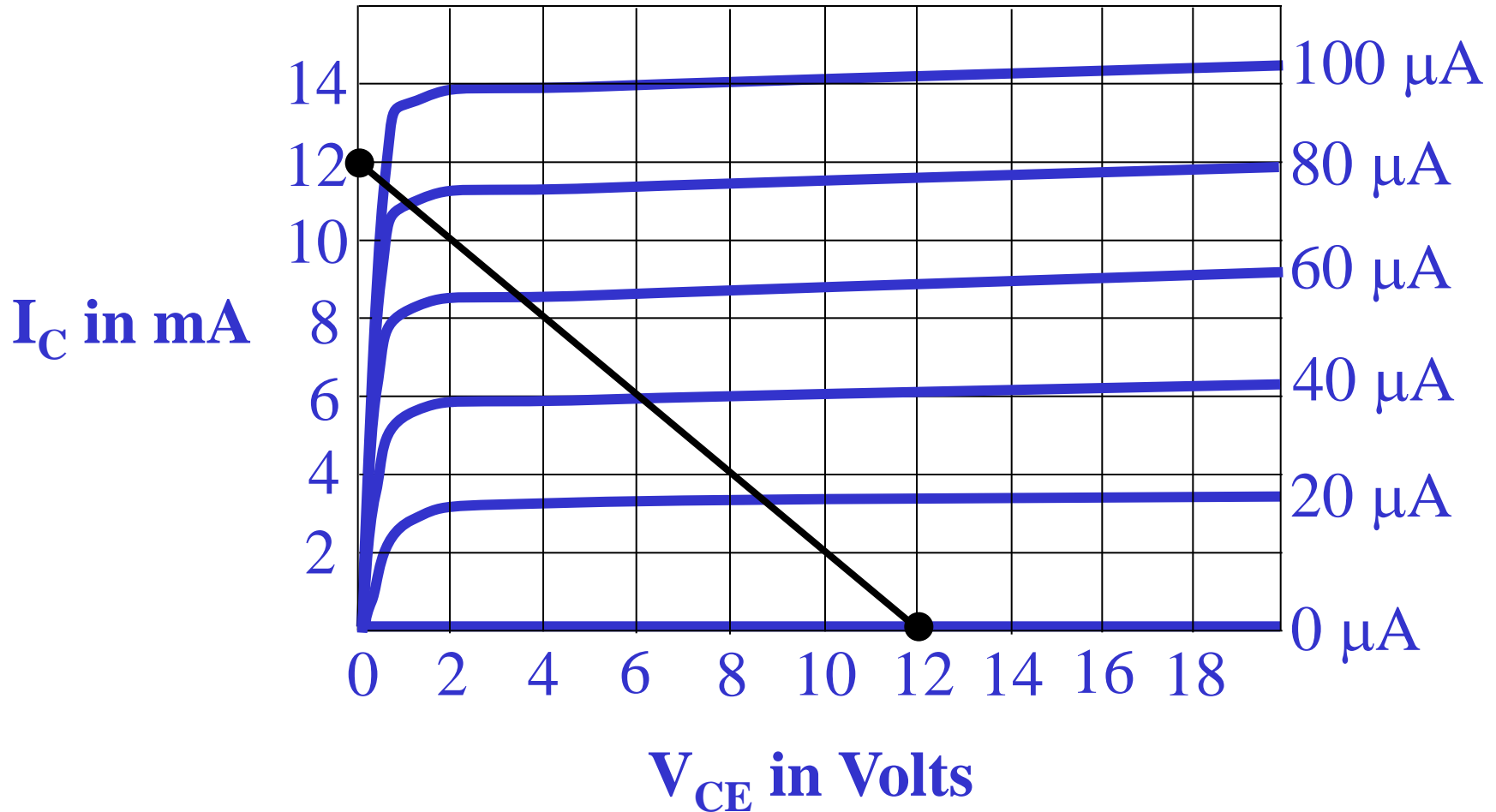


The operating point is called the Q or quiescent point.



This Q point is in the linear region.

Saturation and cutoff are non-linear operating points.



These Q points are used in switching applications.

Transistor circuits

- Amplifying and switching
- **Amplifying** – Q point is in the active region
- **Switching** – Q point switches between saturation and cutoff

Recognizing saturation

- **Assume linear operation.**
- **Perform calculations for currents and voltages.**
- **An impossible result means the assumption is false.**
- **An impossible result indicates saturation.**
- **If the ratio of base to collector resistance is 10:1, the transistor is saturated.**

Base bias

- The base current is established by V_{BB} and R_B .
- The collector current is β times larger in linear circuits.
- The transistor current gain will have a large effect on the operating point.
- Transistor current gain is unpredictable.

Transistor switch

- Base bias is used
- The Q point switches between **saturation** and **cutoff**
- Switching circuits, also called **two-state circuits**, are used in digital applications

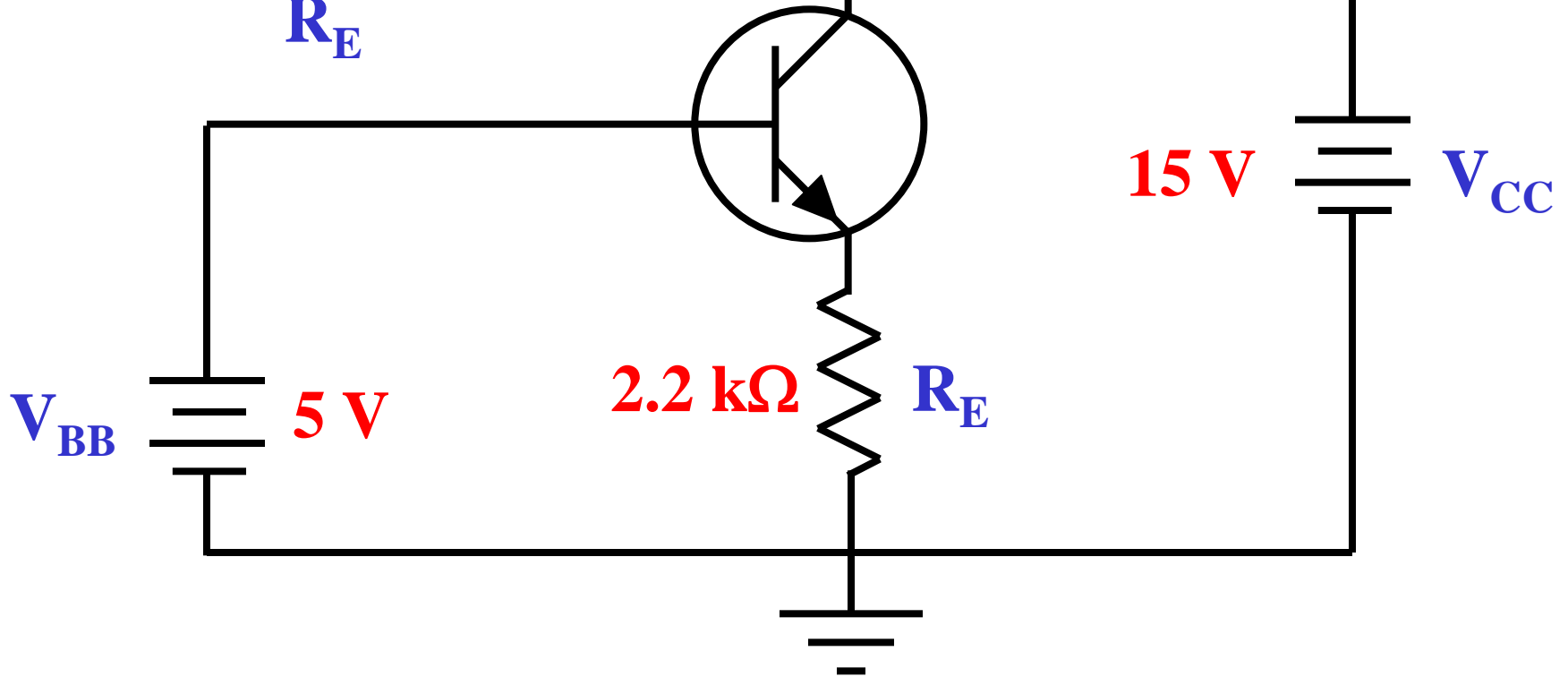
Emitter bias

- The bias resistor is moved from the base to emitter circuit
- Provides Q points that are immune to current gain changes
- Used for linear amplifiers

Emitter bias:

$$I_E = \frac{V_{BB} - V_{BE}}{R_E} = 1.95 \text{ mA}$$

$$I_C \cong I_E \quad 1 \text{ k}\Omega \quad R_C$$



$$V_C = 15 \text{ V} - (1.95 \text{ mA})(1 \text{ k}\Omega) = 13.1 \text{ V}$$

$$V_{CE} = 13.1 \text{ V} - 4.3 \text{ V} = 8.8 \text{ V}$$

Comparing the bias methods

- **Base bias is subject to variations in transistor current gain.**
- **Base bias is subject to temperature effects.**
- **Emitter bias almost eliminates these effects.**
- **The transistor current gain is not required when solving circuits with emitter bias.**

Linear troubleshooting tips

- **The difference between collector and emitter should be more than 1 V but less than V_{CC} .**
- **V_{BE} should be 0.6 to 0.7 V.**
- **V_{BE} can be 1 V or more in high-current circuits.**
- **Both open and shorted junctions are possible.**

Troubleshooting a transistor

- Ohmmeter resistance tests
- DMM resistance or h_{FE} function tests
- In-circuit voltage measurements

Optoelectronic devices

- A **phototransistor** has current gain and is more sensitive than a photodiode
- Combined with an LED, a phototransistor provides a more sensitive **optocoupler**